

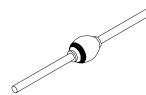
Maximum Ratings		Symbol	Value	Units	
Peak Repetitive Reverse and DC Blocking Voltage		SPD502 SPD503 SPD504 SPD505 SPD506	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200 300 400 500 600	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, $T_A = 25^{\circ}C$ )			Іо	5	Amps
<b>Surge Current</b> (8.3 ms Pulse, Half Sine Wave Superimposed on Io, Allow Junction to Reach Equilibrium between Pulses, $T_A = 25^{\circ}C$ )			I <sub>FSM</sub>	100	Amps
Operating & Storage Temperature		Top & Tstg	-65 to +175	°C	
Maximum Thermal Resistance		ion to Lead, L=3/8" Junction to End Tab	R <sub>θJL</sub> R <sub>θJE</sub>	15 10	°C/W

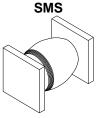
Notes:

1/ For Ordering Information, Price, Operating Curves, and Availability – Contact Factory.

2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.

## **Axial Leaded**



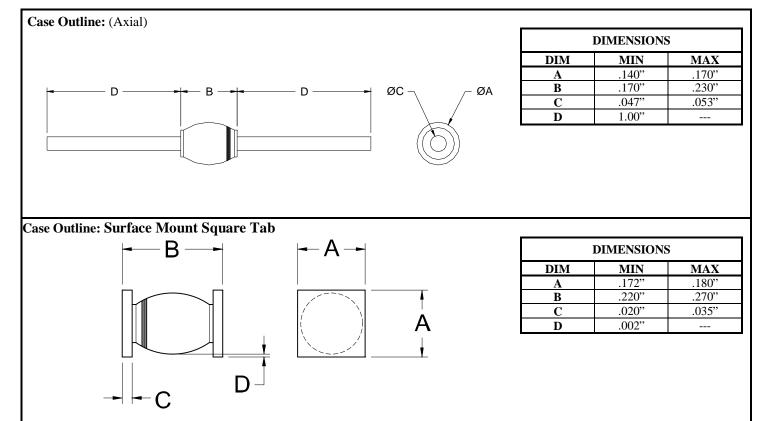




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## SPD502-SPD506 and SPD502SMS - SPD506SMS

Electrical Characteristics	Symbol	Max	Units
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 5 \text{ Adc}, T_A = 25^{\circ}\text{C}, 300 \mu\text{s} \text{ pulse}$ )	$V_{\rm F}$	1.6	Vdc
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 5Adc, T_A = -55^{\circ}C, 300 \ \mu s \ pulse$ )	$\mathbf{V}_{\mathbf{F}}$	1.75	Vdc
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 25^{\circ}$ C, 300 µs pulse minimum)	I <sub>R</sub>	10	μΑ
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 100^{\circ}$ C, 300 µs pulse minimum)	I <sub>R</sub>	1	mA
Junction Capacitance ( $V_R = 10$ Vdc, $T_A = 25^{\circ}$ C, $f = 1$ MHz)	CJ	50	pF
Reverse Recovery Time ( $I_F = 500$ mA, $I_R = 1A$ , $I_{RR} = 0.25A$ , $T_A = 25$ °C)	t <sub>rr</sub>	40	nsec



<b>NOTE:</b> All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RH0105B	DOC
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